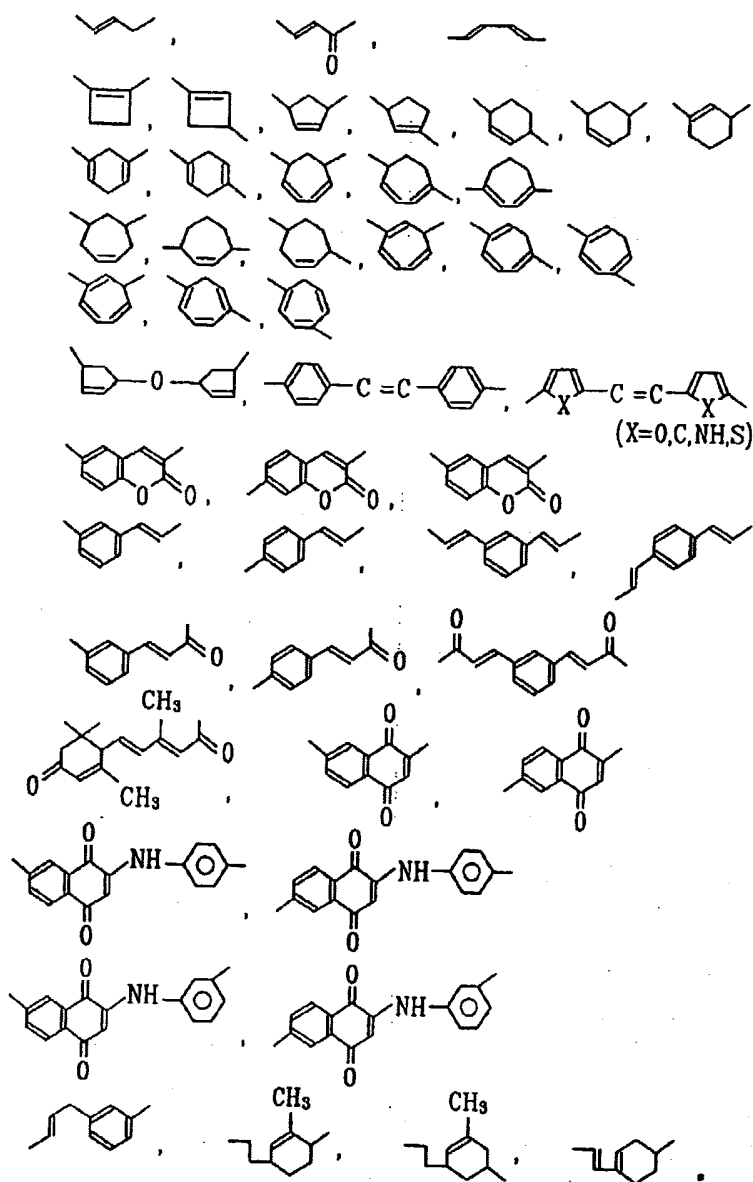{Chemical Formula 2}

20. (Original) The method of claim 19, wherein components B and C are selected

independently from groups shown in chemical formula 3, substituted-structure groups of the

chemical formula 3 with a halogen, cyano, nitro, amino group, other substituted-structure groups

ethenyl group, is selected from groups designated in chemical formula 2, substituted-structure

groups of chemical formula 2 with a halogen, cyano, nitro, amino group, and other substituted-

structure groups with a alkyl and haloalkyl, and cyanoalkyl group having 1 to 10 carbons or an

aryl, alkyl, aryl, haloaryl, haloalkyl aryl, nitroaryl, cyanoaryl group having 3 to 8 carbons;

{Chemical Formula 2}

(X=O,C,NH,S)

27. (Original) The method of claim 26, wherein components B and C are selected from groups shown in chemical formula 3, substituted-structure groups of chemical formula 3 with a halogen, c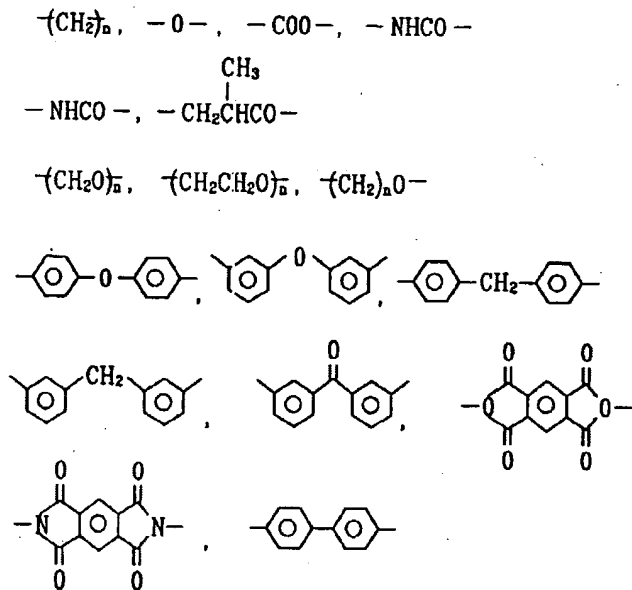yano, nitro, amino group, other substituted-structure groups with carbonated groups of which carbon number n lies between 1 and 10 such as an alkyl, haloalkyl, and cyanoalkyl, and other carbonated groups of which carbon number lies between 3 and 8 such as an alkylaryl, haloaryl, haloalkyl aryl, nitroaryl, cyanoaryl;

{Chemical Formula 3}

28. (Original) The method of claim 25, further comprising:

forming a gate line and a crossing data line on the first substrate;

forming a thin film transistor at a crossing between the gate and data lines; and

forming a pixel electrode connected to the thin film transistor.